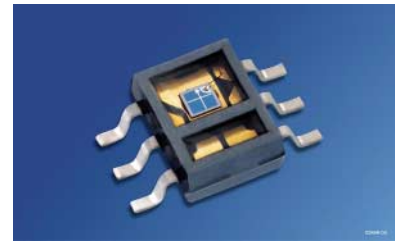


NPN-Silizium-Fototransistor im SMT-Gehäuse

Silicon NPN Phototransistor in SMT Package

Lead (Pb) Free Product - RoHS Compliant

SFH 3201



Wesentliche Merkmale

- Speziell geeignet für Anwendungen im Bereich von 460 nm bis 1080 nm
- Hohe Linearität
- Nur gegurtet lieferbar

Anwendungen

- Umgebungslicht-Detektor
- Lichtschranken für Gleich- und Wechsellichtbetrieb
- Industrieelektronik
- „Messen/Steuern/Regeln“

Features

- Especially suitable for applications from 460 nm to 1080 nm
- High linearity
- Available only on tape and reel

Applications

- Ambient light detector
- Photointerrupters
- Industrial electronics
- For control and drive circuits

Typ Type	Bestellnummer Ordering Code
SFH 3201	Q65110A1207
SFH 3201-2/3	Q65110A2479

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{op}; T_{stg}$	- 40 ... + 100	°C
Kollektor-Emitterspannung Collector-emitter voltage	V_{CE}	20	V
Kollektor-Emitterspannung, $t < 120$ s Collector-emitter voltage	V_{CE}	70	V
Kollektorstrom Collector current	I_C	50	mA
Kollektorspitzenstrom, $\tau < 10$ μ s Collector surge current	I_{CS}	100	mA
Emitter-Kollektorspannung Emitter-collector voltage	V_{EC}	7	V
Verlustleistung, $T_A = 25$ °C Total power dissipation	P_{tot}	120	mW
Wärmewiderstand für Montage auf PC-Board Thermal resistance for mounting on pcb	R_{thJA}	500	K/W

Kennwerte ($T_A = 25\text{ °C}$)**Characteristics**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S\text{ max}}$	850	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von S_{max} Spectral range of sensitivity $S = 10\%$ of S_{max}	λ	460 ... 1080	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	A	0.55	mm ²
Abmessung der Chipfläche Dimensions of chip area	$L \times B$ $L \times W$	1×1	mm × mm
Halbwinkel Half angle	φ	± 60	Grad deg.
Kapazität, $V_{CE} = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$ Capacitance	C_{CE}	15	pF
Dunkelstrom Dark current $V_{CE} = 20\text{ V}$, $E = 0$	I_{CEO}	3 (≤ 200)	nA

Die Fototransistoren werden nach ihrer Fotoempfindlichkeit gruppiert und mit arabischen Ziffern gekennzeichnet.

The phototransistors are grouped according to their spectral sensitivity and distinguished by arabian figures.

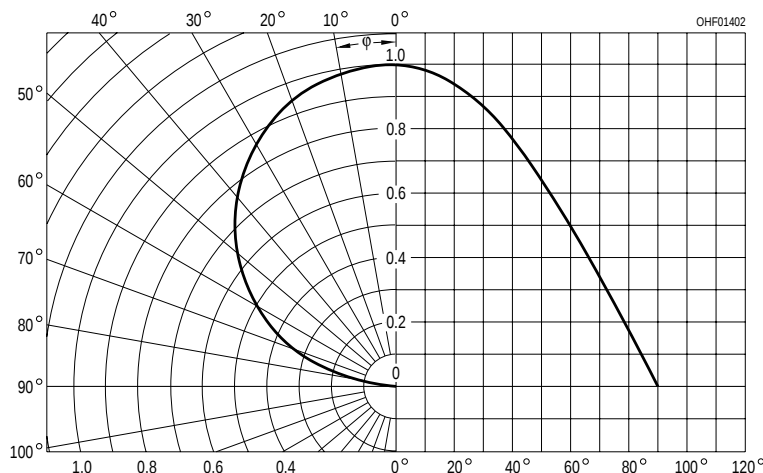
Bezeichnung Parameter	Symbol Symbol	Wert Value			Einheit Unit
		-1	-2	-3	
Fotostrom, $\lambda = 950 \text{ nm}$ Photocurrent $E_e = 0.1 \text{ mW/cm}^2$, $V_{CE} = 5 \text{ V}$ $E_v = 1000 \text{ lx}$, Normlicht/ standard light A, $V_{CE} = 5 \text{ V}$	I_{PCE} I_{PCE}	63 ... 125 1.65	100 ... 200 2.6	160 ... 320 4.2	μA mA
Anstiegszeit/Abfallzeit Rise and fall time $I_C = 1 \text{ mA}$, $V_{CC} = 5 \text{ V}$, $R_L = 1 \text{ k}\Omega$	t_r , t_f	16	24	34	μs
Kollektor-Emitter- Sättigungsspannung Collector-emitter saturation voltage $I_C = I_{PCEmin}^{1)} \times 0.3$, $E_e = 0.1 \text{ mW/cm}^2$	V_{CEsat}	170 (≤ 250)	170 (≤ 250)	170 (≤ 250)	mV

¹⁾ I_{PCEmin} ist der minimale Fotostrom der jeweiligen Gruppe.

¹⁾ I_{PCEmin} is the min. photocurrent of the specified group.

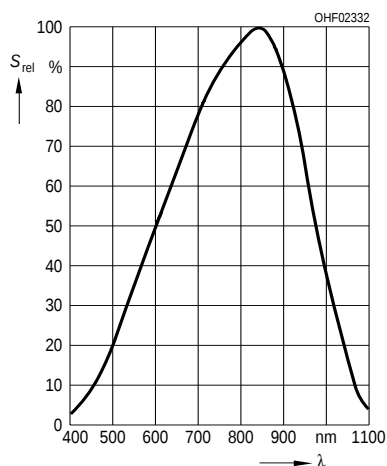
Directional Characteristics

$$S_{rel} = f(\varphi)$$



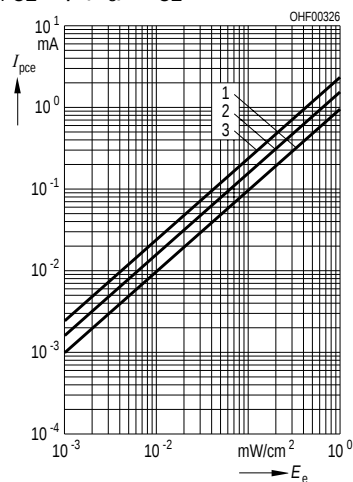
$T_A = 25\text{ °C}$, $\lambda = 950\text{ nm}$

Rel. Spectral Sensitivity,
 $S_{\text{rel}} = f(\lambda)$



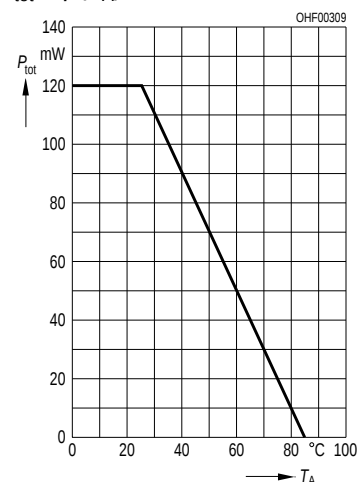
Photocurrent

$I_{\text{PCE}} = f(E_e)$, $V_{\text{CE}} = 5\text{ V}$

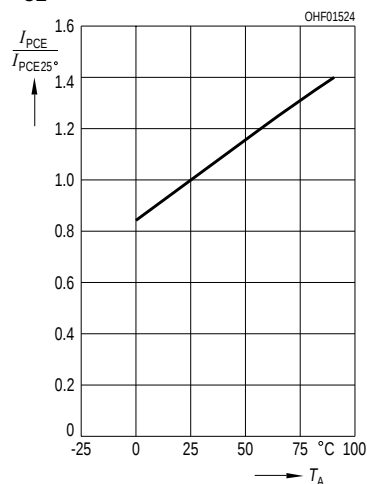


Total Power Dissipation

$P_{\text{tot}} = f(T_A)$

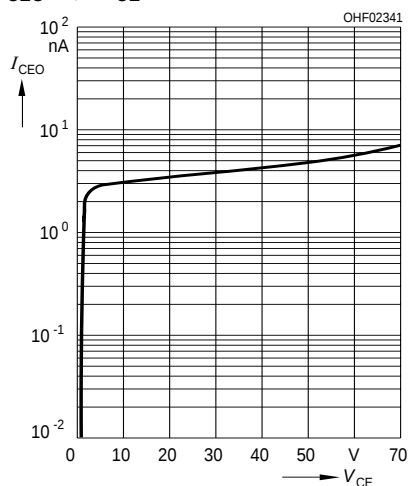


Photocurrent $I_{\text{PCE}} = f(T_A)$,
 $V_{\text{CE}} = 5\text{ V}$, normalized to 25 °C



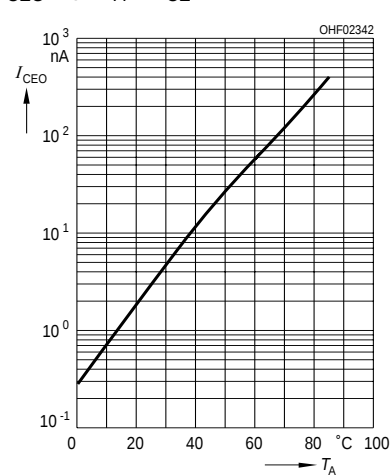
Dark Current

$I_{\text{CEO}} = f(V_{\text{CE}})$, $E = 0$



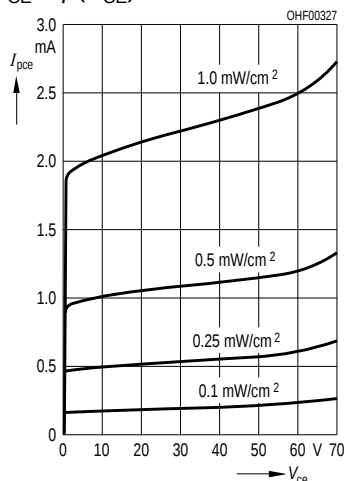
Dark Current

$I_{\text{CEO}} = f(T_A)$, $V_{\text{CE}} = 10\text{ V}$, $E = 0$



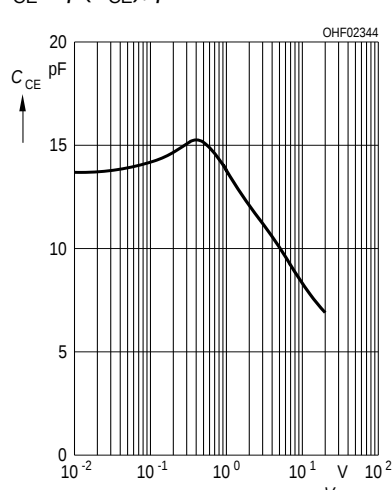
Photocurrent

$I_{\text{PCE}} = f(V_{\text{CE}})$

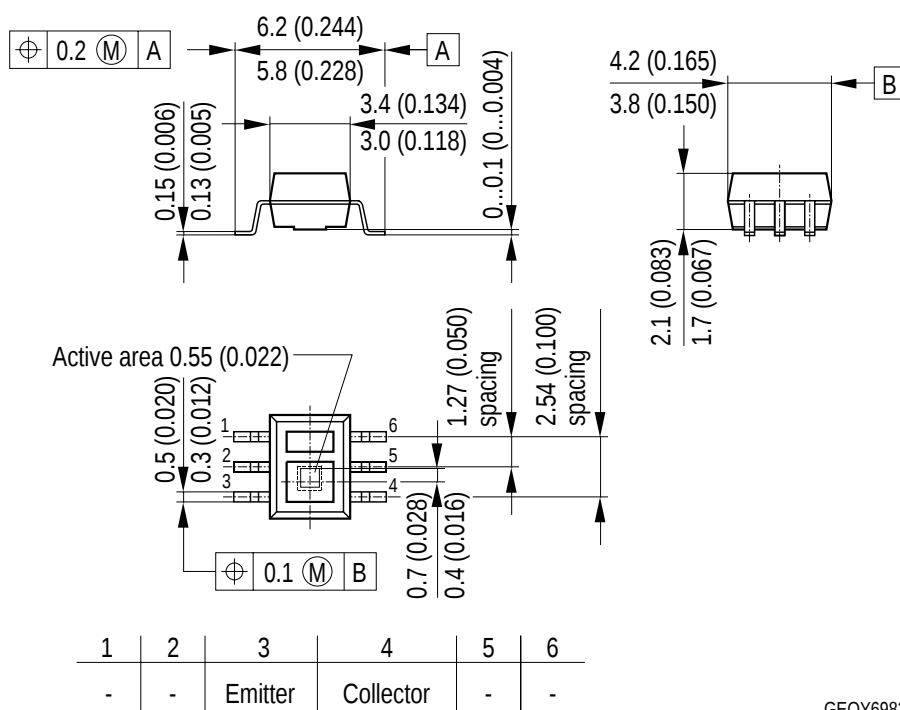


Collector-Emitter Capacitance

$C_{\text{CE}} = f(V_{\text{CE}})$, $f = 1\text{ MHz}$



Maßzeichnung Package Outlines

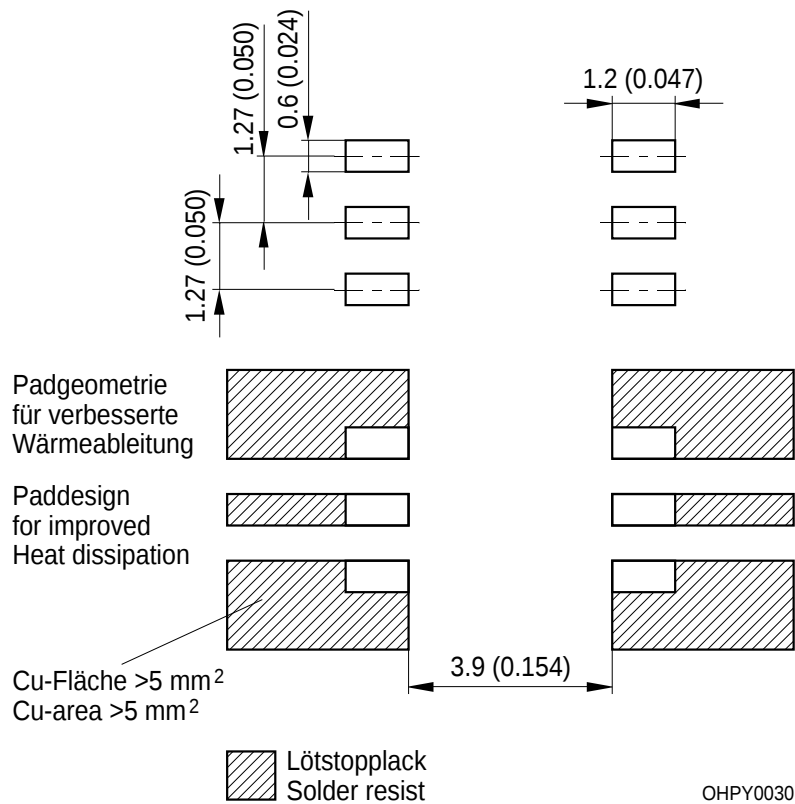


GEOY6982

Maße in mm (inch) / Dimensions in mm (inch).

Empfohlenes Lötpaddesign
Recommended Solder Pad

Reflow Löten
Reflow Soldering



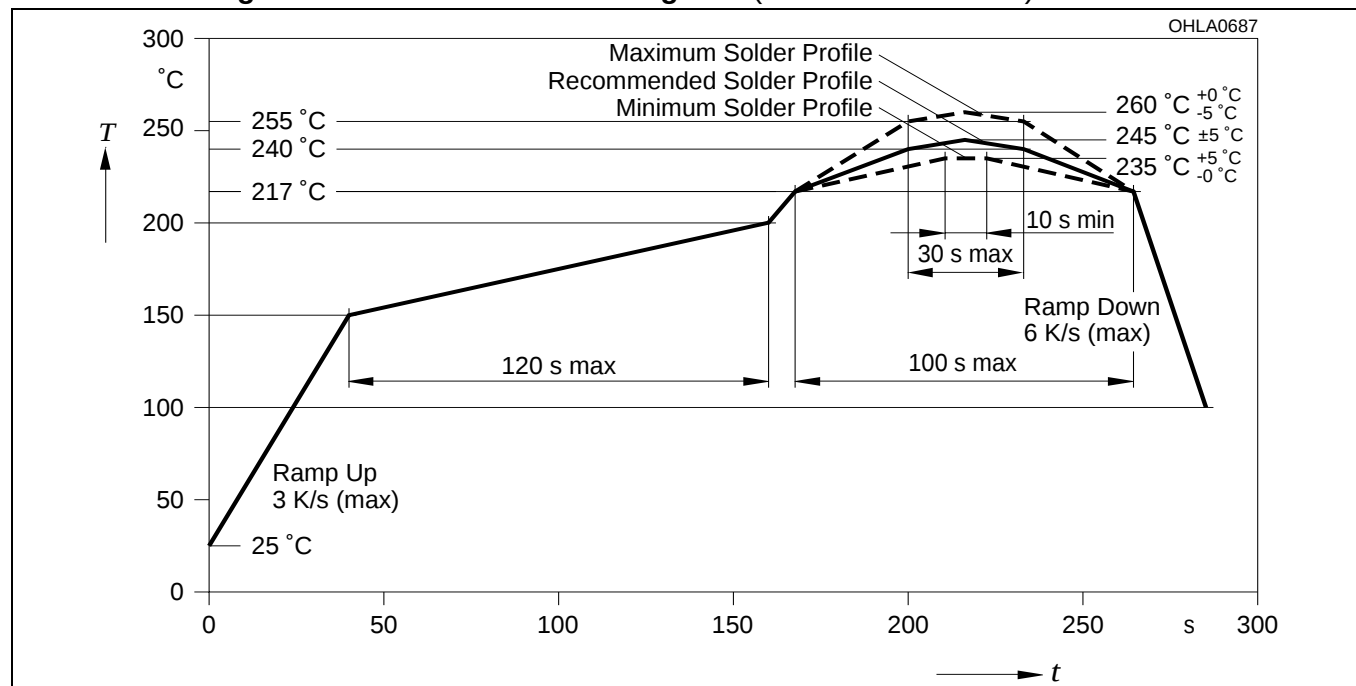
Lötbedingungen**Soldering Conditions****Reflow Lötprofil für bleifreies Löten****Reflow Soldering Profile for lead free soldering**

Vorbehandlung nach JEDEC Level 4

Preconditioning acc. to JEDEC Level 4

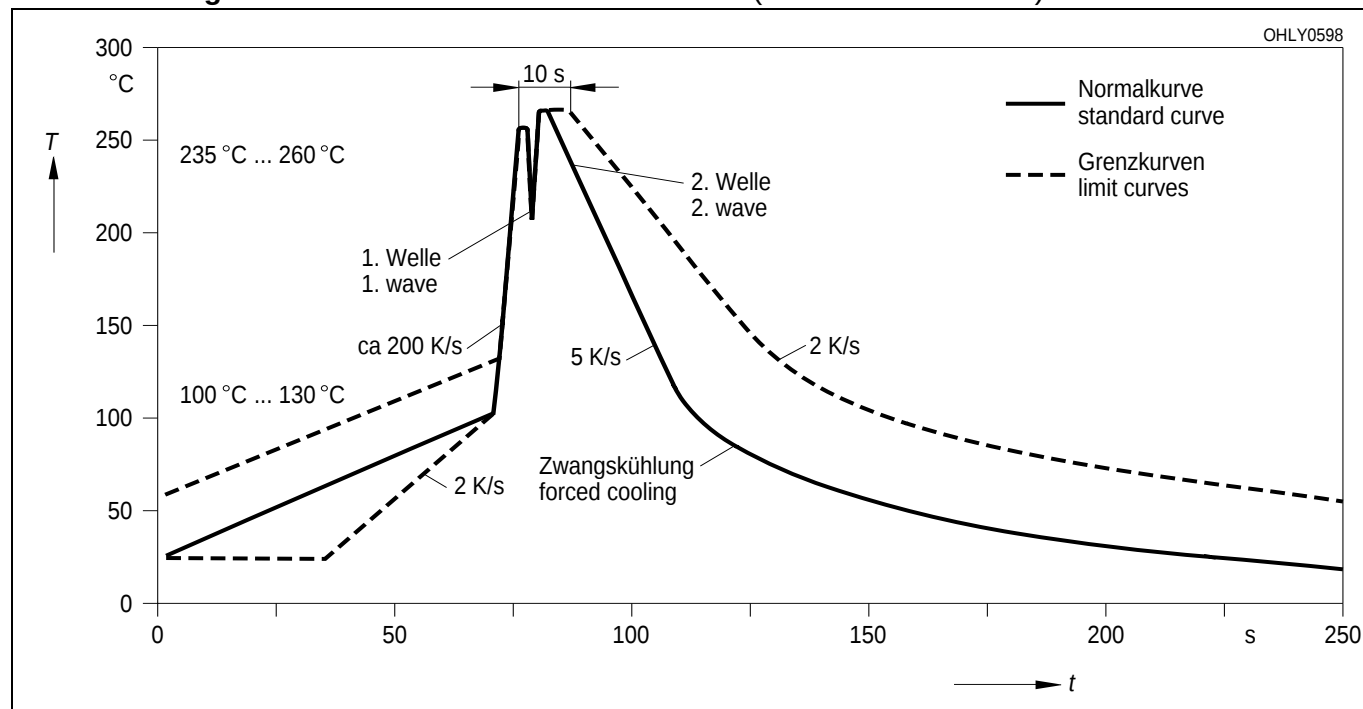
(nach J-STD-020C)

(acc. to J-STD-020C)

**Wellenlöten (TTW)****TTW Soldering**

(nach CECC 00802)

(acc. to CECC 00802)



Published by
OSRAM Opto Semiconductors GmbH
Wernerwerkstrasse 2, D-93049 Regensburg
www.osram-os.com

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